

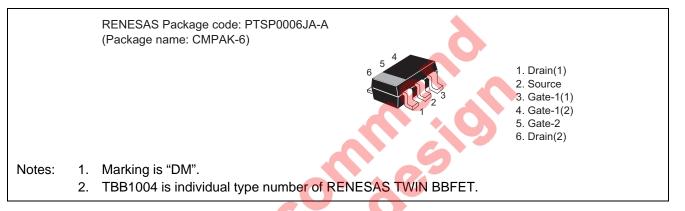
# Twin Built in Biasing Circuit MOS FET IC VHF/UHF RF Amplifier

R07DS0314EJ1200 (Previous: REJ03G0842-1100) Rev.12.00 Mar 28, 2011

# Features

- Small SMD package CMPAK-6 built in twin BBFET; To reduce using parts cost & PC board space.
- Suitable for World Standard Tuner RF amplifier.
- Very useful for total tuner cost reduction.
- Withstanding to ESD; Built in ESD absorbing diode. Withstand up to 200V at C=200pF, Rs=0 conditions.
- Provide mini mold packages; CMPAK-6

# Outline



# Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem 🗧	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DS</sub>	6	V
Gate1 to source voltage	V <sub>G1S</sub>	+6	V
		-0	
Gate2 to source voltage	V <sub>G2S</sub>	+6	V
		-0	
Drain current	ID	30	mA
Channel power dissipation	Pch <sup>*3</sup>	250	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 3. Value on the glass epoxy board (49mm  $\times$  38mm  $\times$  1mm).



# **Electrical Characteristics**

#### The below specification are applicable for UHF unit (FET1)

						(Ta = 25°C)
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	6	—	—	V	$I_D = 200 \ \mu A, \ V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	V <sub>(BR)G1SS</sub>	+6	—	—	V	$I_{G1}$ = +10 $\mu$ A, $V_{G2S}$ = $V_{DS}$ = 0
Gate2 to source breakdown voltage	V <sub>(BR)G2SS</sub>	+6	—	—	V	$I_{G2}$ = +10 $\mu$ A, $V_{G1S}$ = $V_{DS}$ = 0
Gate1 to source cutoff current	I <sub>G1SS</sub>	—	—	+100	nA	$V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I <sub>G2SS</sub>	—	—	+100	nA	$V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V <sub>G1S(off)</sub>	0.5	0.7	1.0	V	$V_{DS} = 5 V, V_{G2S} = 4 V$
						I <sub>D</sub> = 100 μA
Gate2 to source cutoff voltage	V <sub>G2S(off)</sub>	0.5	0.7	1.0	V	$V_{DS} = 5 V, V_{G1S} = 5 V$
						I <sub>D</sub> = 100 μA
Drain current	I <sub>D(op)</sub>	13	17	21	mA	$V_{DS} = 5 V, V_{G1} = 5 V$
						$V_{G2S}$ = 4 V, $R_G$ = 100 k $\Omega$
Forward transfer admittance	y <sub>fs</sub>	21	26	31	mS	$V_{DS} = 5 V, V_{G1} = 5 V, V_{G2S} = 4 V$
						$R_G = 100 \text{ k}\Omega$ , f = 1 kHz
Input capacitance	Ciss	1.4	1.8	2.2	pF	$V_{DS} = 5 V, V_{G1} = 5 V$
Output capacitance	Coss	1.0	1.4	1.8	pF	$V_{G2S} = 4 \text{ V}, \text{ R}_{G} = 100 \text{ k}\Omega$
Reverse transfer capacitance	Crss	_	0.02	0.04	pF	f = 1 MHz
Power gain	PG	16	21		dB	$V_{DS} = V_{G1} = 5 V, V_{G2S} = 4 V$
Noise figure	NF		1.7	2.5	dB	R <sub>G</sub> = 100 kΩ, f = 900 MHz
						Zi = S11*, Zo = S22*(:PG)
						Zi = S11opt (:NF)

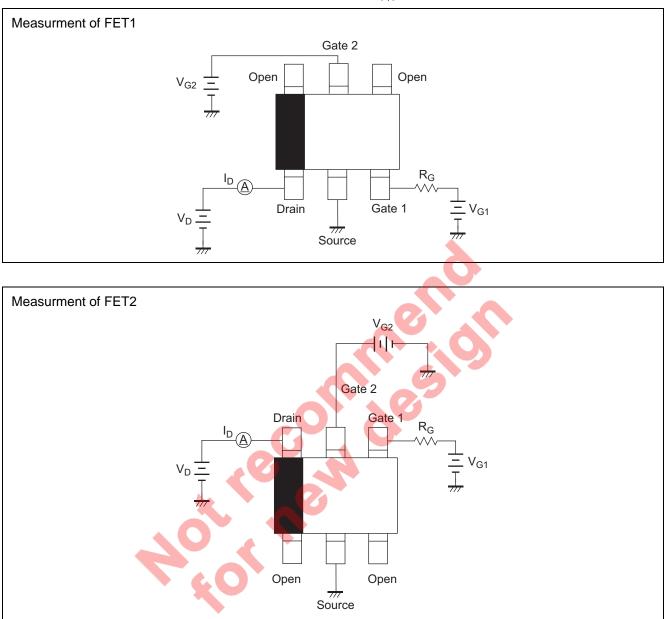
#### The below specification are applicable for VHF unit (FET2)

 $(Ta = 25^{\circ}C)$ Symbol Min Unit **Test conditions** Item Тур Max Drain to source breakdown voltage V<sub>(BR)DSS</sub> 6 V  $I_D = 200 \; \mu A, \, V_{G1S} = V_{G2S} = 0$ Gate1 to source breakdown voltage +6 V  $I_{G1} = +10 \; \mu A, \; V_{G2S} = V_{DS} = 0$ V<sub>(BR)G1SS</sub> \_ Gate2 to source breakdown voltage +6 \_\_\_\_ V  $I_{G2} = +10 \; \mu A, \, V_{G1S} = V_{DS} = 0$ V<sub>(BR)G2SS</sub> Gate1 to source cutoff current +100 nA  $V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0$ I<sub>G1SS</sub> \_ +100  $V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$ Gate2 to source cutoff current I<sub>G2SS</sub> \_ nA 0.5 0.75 1.0 V  $V_{DS} = 5 V, V_{G2S} = 4 V$ Gate1 to source cutoff voltage V<sub>G1S(off)</sub>  $I_{D} = 100 \ \mu A$ 0.5 0.75 1.0 V  $V_{DS} = 5 V, V_{G1S} = 5 V$ Gate2 to source cutoff voltage  $V_{\text{G2S(off)}}$  $I_{D} = 100 \ \mu A$  $V_{DS} = 5 V, V_{G1} = 5 V$ Drain current 16 20 24 mΑ I<sub>D(op)</sub>  $V_{G2S}$  = 4 V,  $R_G$  = 100 k $\Omega$  $V_{DS} = 5 V, V_{G1} = 5 V, V_{G2S} = 4 V$ Forward transfer admittance y<sub>fs</sub> 27 32 37 mS  $R_G = 100 \text{ k}\Omega, f = 1 \text{ kHz}$ Input capacitance Ciss 2.3 2.7 3.1 pF  $V_{DS} = 5 V, V_{G1} = 5 V$ 1.4 1.8 2.2 pF  $V_{G2S} = 4 V, R_G = 100 k\Omega$ Output capacitance Coss f = 1 MHzReverse transfer capacitance Crss 0.03 0.05 pF  $V_{DS} = V_{G1} = 5 V, V_{G2S} = 4 V$ Power gain PG 24 29 dB Noise figure NF \_\_\_\_ 1.2 1.7 dB  $R_G = 100 \text{ k}\Omega$ , f = 200 MHz



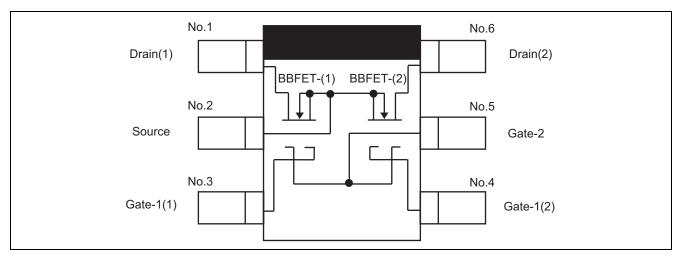
# **Test Circuits**

• DC Biasing Circuit for Operating Characteristic Items (I<sub>D(op)</sub>, |yfs|, Ciss, Coss, Crss, NF, PG)

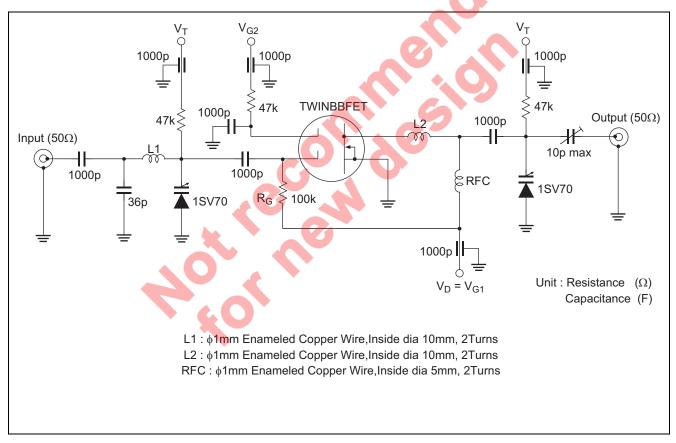




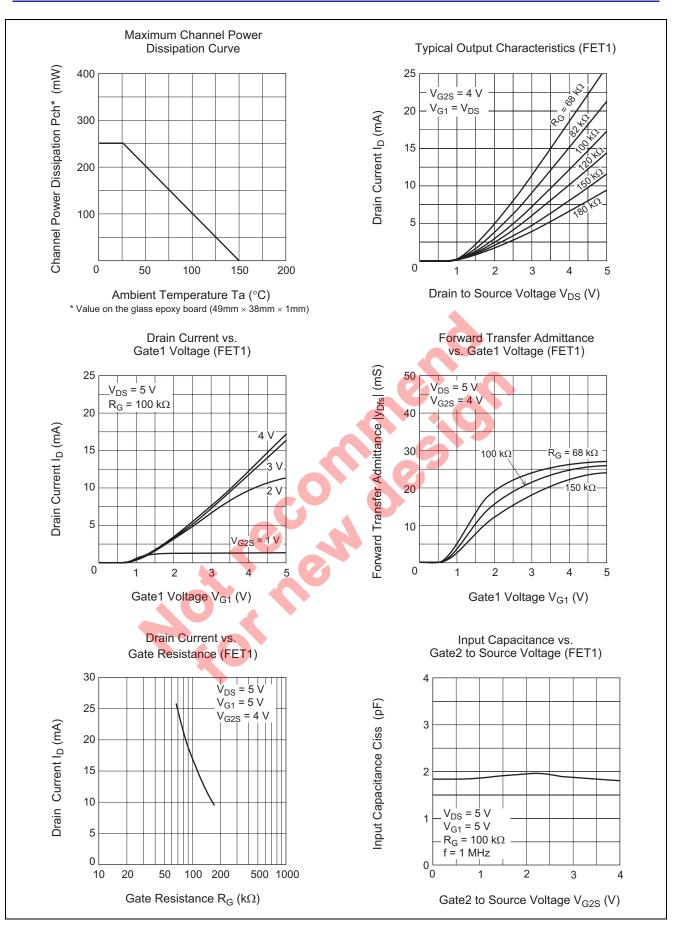
#### • Equivalent Circuit



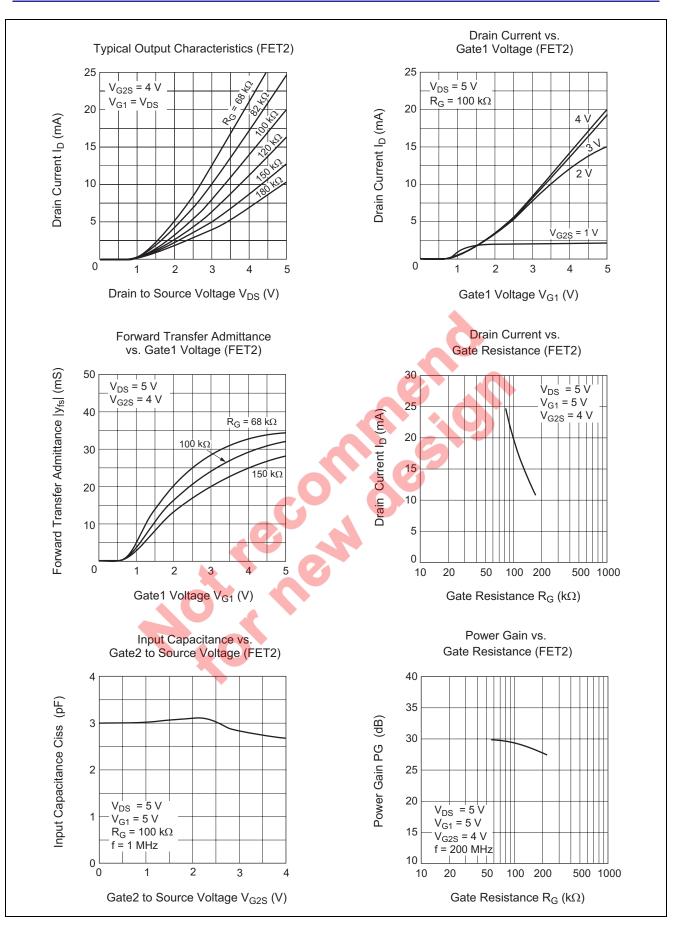
#### • 200 MHz Power Gain, Noise Figure Test Circuit

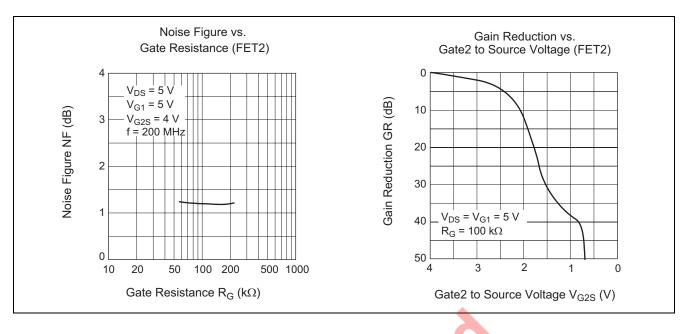






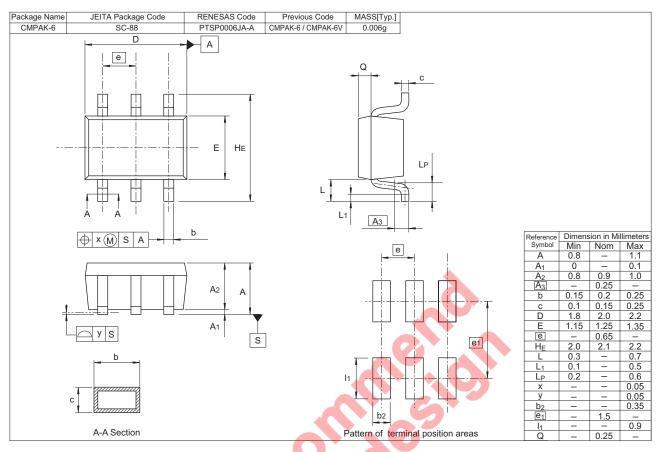








# **Package Dimensions**



### **Ordering Information**

Orderable Part Number		C	Quantity		5	Shipping Container
TBB1004DMTL-E	3000			(	φ 178	8 mm Reel, 8 mm Emboss Taping
TBB1004DMTL-H		X				

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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